

Vishay General Semiconductor

Surface Mount TRANSZORB® Transient Voltage Suppressors



DO-215AB (SMCG)

PRIMARY CHARACTERISTICS					
V _{BR} uni-directional	6.40 V to 231 V				
V _{BR} bi-directional	6.40 V to 231 V				
V _{WM}	5.0 V to 188 V				
P _{PPM}	1500 W				
P _D	6.5 W				
I _{FSM} (uni-directional only)	200 A				
T _J max.	150 °C				
Polarity	Uni-directional, bi-directional				
Package	DO-215AB (SMCG)				

DEVICES FOR BI-DIRECTION APPLICATIONS

For bi-directional devices use CA suffix (e.g. SMCG188CA). Electrical characteristics apply in both directions.

FEATURES

- Low profile package
- Ideal for automated placement
- · Glass passivated chip junction
- Available in uni-directional and bi-directional
- · Excellent clamping capability
- Very fast response time
- Low incremental surge resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, automotive, and telecommunication.

MECHANICAL DATA

Case: DO-215AB (SMCG)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade Base P/NHE3 - RoHS compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: For uni-directional types the band denotes cathode end, no marking on bi-directional types

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation with a 10/1000 μs waveform ⁽¹⁾⁽²⁾	P _{PPM}	1500	W			
Peak pulse current with a 10/1000 μs waveform ⁽¹⁾	I _{PPM}	See next table	А			
Peak forward surge current 8.3 ms single half sine-wave uni-directional only (2)	I _{FSM}	200	А			
Power dissipation on infinite heatsink, T _A = 50 °C	P _D	6.5	W			
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150	°C			

Notes

- ⁽¹⁾ Non-repetitive current pulse, per fig. 3 and derated above $T_A = 25$ °C per fig. 2.
- (2) Mounted on 0.31" x 0.31" (8.0 mm x 8.0 mm) copper pads to each terminal

SMCG5.0A thru SMCG188CA

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)									
DEVICE TYPE MODIFIED GULL WING		MARKING DDE	VOLT V _{BR} A	(DOWN FAGE T I _T ⁽¹⁾ V)	TEST CURRENT I _T (mA)	STAND-OFF VOLTAGE V _{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V _{WM}	MAXIMUM PEAK PULSE SURGE CURRENT	MAXIMUM CLAMPING VOLTAGE AT I _{PPM}
	UNI	BI	MIN.	MAX.	(112-4)	(•)	I _D (μΑ) ⁽³⁾	I _{PPM} (A) ⁽²⁾	V _C (V)
(+)SMCG5.0A (5)	GDE	GDE	6.40	7.07	10	5.0	1000	163.0	9.20
(+)SMCG6.0A	GDG	GDG	6.67	7.37	10	6.0	1000	145.6	10.3
⁽⁺⁾ SMCG6.5A	GDK	BDK	7.22	7.98	10	6.5	500	133.9	11.2
(+)SMCG7.0A	GDM	GDM	7.78	8.60	10	7.0	200	125.0	12.0
(+)SMCG7.5A	GDP	BDP	8.33	9.21	1.0	7.5	100	116.3	12.9
(+)SMCG8.0A	GDR	BDR	8.89	9.83	1.0	8.0	50	110.3	13.6
(+)SMCG8.5A	GDT	BDT	9.44	10.4	1.0	8.5	20	104.2	14.4
(+)SMCG9.0A	GDV	BDV	10.0	11.1	1.0	9.0	10	97.4	15.4
(+)SMCG10A	GDX	BDX	11.1	12.3	1.0	10	5.0	88.2	17.0
(+)SMCG11A	GDZ	GDZ	12.2	13.5	1.0	11	5.0	82.4	18.2
(+)SMCG12A	GEE	BEE	13.3	14.7	1.0	12	5.0	75.4	19.9
(+)SMCG13A	GEG	GEG	14.4	15.9	1.0	13	1.0	69.8	21.5
(+)SMCG14A	GEK	BEK	15.6	17.2	1.0	14	1.0	64.7	23.2
(+)SMCG15A	GEM	BEM	16.7	18.5	1.0	15	1.0	61.5	24.4
(+)SMCG16A	GEP	GEP	17.8	19.7	1.0	16	1.0	57.7	26.0
(+)SMCG17A	GER	GER	18.9	20.9	1.0	17	1.0	54.3	27.6
(+)SMCG18A	GET	BET	20.0	22.1	1.0	18	1.0	51.4	29.2
(+)SMCG20A	GEV	BEV	22.2	24.5	1.0	20	1.0	46.3	32.4
(+)SMCG22A	GEX	BEX	24.4	26.9	1.0	22	1.0	42.3	35.5
(+)SMCG24A	GEZ	BEZ	26.7	29.5	1.0	24	1.0	38.6	38.9
(+)SMCG26A	GFE	BFE	28.9	31.9	1.0	26	1.0	35.6	42.1
(+)SMCG28A	GFG	BFG	31.1	34.4	1.0	28	1.0	33.0	45.4
(+)SMCG30A	GFK	BFK	33.3	36.8	1.0	30	1.0	31.0	48.4
(+)SMCG33A	GFM	BFM	36.7	40.6	1.0	33	1.0	28.1	53.3
(+)SMCG36A	GFP	BFP	40.0	44.2	1.0	36	1.0	25.8	58.1
(+)SMCG40A	GFR	BFR	44.4	49.1	1.0	40	1.0	23.3	64.5
(+)SMCG43A	GFT	BFT	47.8	52.8	1.0	43	1.0	21.6	69.4
(+)SMCG45A	GFV	GFV	50.0	55.3	1.0	45	1.0	20.6	72.7
(+)SMCG48A	GFX	GFX	53.3	58.9	1.0	48	1.0	19.4	77.4
(+)SMCG51A	GFZ	GFZ	56.7	62.7	1.0	51	1.0	18.2	82.4
(+)SMCG54A	GGE	GGE	60.0	66.3	1.0	54	1.0	17.2	87.1
(+)SMCG58A	GGG	GGG	64.4	71.2	1.0	58	1.0	16.0	93
(+)SMCG60A	GGK	GGK	66.7	73.7	1.0	60	1.0	15.5	96
(+)SMCG64A	GGM	GGM	71.1	78.6	1.0	64	1.0	14.6	103
(+)SMCG70A	GGP	GGP	77.8	86.0	1.0	70	1.0	13.3	113
(+)SMCG75A	GGR	GGR	83.3	92.1	1.0	75	1.0	12.4	121
(+)SMCG78A	GGT	GGT	86.7	95.8	1.0	78	1.0	11.9	126
(+)SMCG85A	GGV	GGV	94.4	104	1.0	85	1.0	10.9	137
(+)SMCG90A	GGX	GGX	100	111	1.0	90	1.0	10.3	146
(+)SMCG100A	GGZ	GGZ	111	123	1.0	100	1.0	9.3	162
(+)SMCG110A	GHE	GHE	122	135	1.0	110	1.0	8.5	177
(+)SMCG120A	GHG	GHG	133	147	1.0	120	1.0	7.8	193
(+)SMCG130A	GHK	GHK	144	159	1.0	130	1.0	7.2	209
(+)SMCG150A	GHM	GHM	167	185	1.0	150	1.0	6.2	243
(+)SMCG160A	GHP	GHP	178	197	1.0	160	1.0	5.8	259
(+)SMCG170A	GHR	GHR	189	209	1.0	170	1.0	5.5	275
SMCG188A	GHS	GHS	209	231	1.0	188	1.0	4.6	328
SIVICG 100A	чпо	GITO	209	20 I	1.0	100	1.0	4.0	320

Notes

- ⁽¹⁾ Pulse test: $t_p \le 50 \text{ ms}$
- $\ensuremath{^{(2)}}$ Surge current waveform per fig. 3 and derate per fig. 2
- $^{(3)}$ For bi-directional types having V_{WM} of 10 V and less, the I_D limit is doubled
- (4) All terms and symbols are consistent with ANSI/IEEE C62.35
- $^{(5)}\,$ For the bi-directional SMCG5.0CA, the maximum V_{BR} is 7.25 V
- $^{(6)}~V_F=3.5~V$ at $I_F=100~A$ (uni-directional only)
- (+) Underwriters laboratory recognition for the classification of protectors (QVGQ2) under the UL standard for safety 497B and file number E136766 for both uni-directional and bi-directional devices



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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Typical thermal resistance, junction to ambient (1)	$R_{ hetaJA}$	75	°C/W			
Typical thermal resistance, junction to lead	$R_{ hetaJL}$	15]			

Note

⁽¹⁾ Measured on minimum recommended pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SMCG5.0A-E3/57T	0.211	57T	850	7" diameter plastic tape and reel		
SMCG5.0A-E3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel		
SMCG5.0AHE3/57T (1)	0.211	57T	850	7" diameter plastic tape and reel		
SMCG5.0AHE3/9AT (1)	0.211	9AT	3500	13" diameter plastic tape and reel		

Note

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

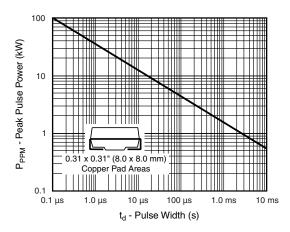


Fig. 1 - Peak Pulse Power Rating Curve

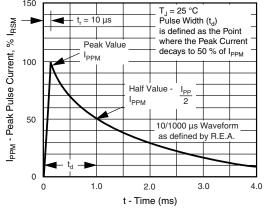


Fig. 3 - Pulse Waveform

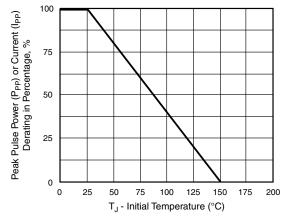


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

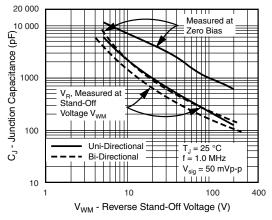


Fig. 4 - Typical Junction Capacitance Uni-Directional

⁽¹⁾ AEC-Q101 qualified





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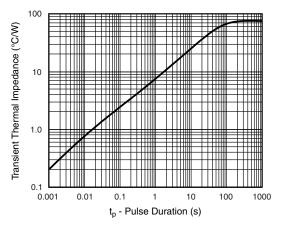


Fig. 5 - Typical Transient Thermal Impedance

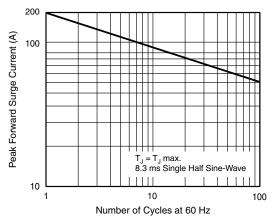
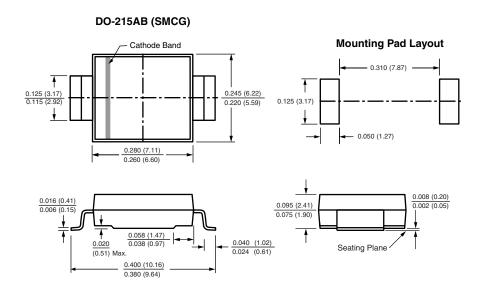


Fig. 6 - Maximum Non-Repetitive Peak Forward Surge Current Uni-Directional Use Only

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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